
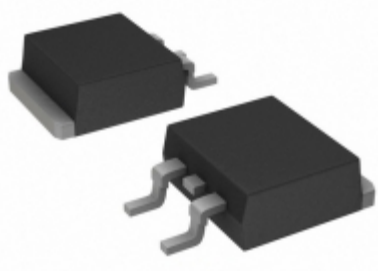


	<p><b>FQB30N06LTM</b></p>
	<p><b>Hersteller-Teilenummer:</b> FQB30N06LTM</p> <p><b>Hersteller / Marke:</b> AMI Semiconductor / ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 60V 32A D2PAK</p> <p><b>Datenblätter:</b>  <a href="#">FQB30N06LTM.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 66520 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FQB30N06LTM
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 32A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	66520 pcs Stock
Hersteller Standard Vorlaufzeit	5 Weeks
detaillierte Beschreibung	N-Channel 60V 32A (Tc) 3.75W (Ta), 79W (Tc) Surface
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.75W (Ta), 79W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	32A (Tc)
Rds On (Max) @ Id, Vgs	35 mOhm @ 16A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	20nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	1040pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FQB30N06LTM-ND



















































FQB30N06LTM ist neu im Original, Suche FQB30N06LTM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB30N06LTM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB30N06LTM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>FQB30N06TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 30A D2PAK</p>	 <p><b>FQB2P40TM</b> Fairchild/ON Semiconductor MOSFET P-CH 400V 2A D2PAK</p>	 <p><b>FQB30N06TM_NL</b> FAIRCHI</p>	 <p><b>FQB30N06</b> FAIRCHI FQB30N06 FAIRCHI</p>
 <p><b>FQB30N06LTM</b> Fairchild/ON Semiconductor MOSFET N-CH 60V 32A D2PAK</p>	 <p><b>FQB30N06L</b> F FQB30N06L F</p>	 <p><b>FQB32N12V2</b> FSC FQB32N12V2 FSC</p>	 <p><b>FQB30N06LTM-NL</b> Fairchild/ON Semiconductor FQB30N06LTM-NL FAIRCHILD</p>

heiße Teile

Mehr

 FQB22P10	 FQB22P10TM	 FQB22P10TM	 FQB22P10TM_F085	 FQB24N08TM
 FQB24N08TM	 FQB25N33	 FQB25N33TM	 FQB25N33TM	 FQB25N33TM_F085
 FQB27N25TM	 FQB27P06	 FQB27P06TM	 FQB27P06TM	 FQB2N50C
 FQB2N60TM	 FQB2N60TM	 FQB2N80TM	 FQB2N80TM	 FQB2NA90TM
 FQB2NA90TM	 FQB2P25TM	 FQB2P25TM	 FQB30N06	 FQB30N06L
 FQB30N06LTM	 FQB30N06TM	 FQB30N06TM	 FQB32N12V2	 FQB32N12V2TM
 FQB32N12V2TM	 FQB32N20	 FQB32N20C	 FQB32N20CTM	 FQB32N20CTM
 FQB32N30	 FQB33N10	 FQB33N10L	 FQB33N10LTM	 FQB33N10LTM
 FQB33N10TM	 FQB33N10TM	 FQB34N20	 FQB34N20L	 FQB34N20LTM
 FQB34N20LTM	 FQB34N20TM	 FQB34N20TM_AM002	 FQB34P10	 FQB34P10TM

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited

